BLF3G22-30

UHF power LDMOS transistor

Rev. 2 — 1 September 2015

AMPLEON

Product data sheet

1. Product profile

1.1 General description

30 W LDMOS power transistor for base station applications at frequencies from 2000 MHz to 2200 MHz

Table 1. Typical class-AB RF performance

 $I_{Dq} = 450$ mA; $T_h = 25$ °C in a common source test circuit.

Mode of operation	f ₁	f ₂	V _{DS}	I_{Dq}	P _{L(PEP)}	$P_{L(AV)}$	Gp	η_D	IMD	ACPR	IMD3
	(MHz)	(MHz)	(V)	(mA)	(W)	(W)	(dB)	(%)	(dBc)	(dBc)	(dBc)
2-tone	2170	2170.1	28	450	36	-	14	34	-24	-	-
2-carrier W-CDMA[1]	2115	2165	28	450	_	6	15	21	-	-42 <mark>[2]</mark>	-38

- [1] 3GPP test model 1; 64 channels with 66 % clippings
- [2] Measured within 10 kHz bandwidth

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features

- Excellent back off linearity
- Typical 2-carrier W-CDMA performance at a supply voltage of 28 V and I_{Dq} of 450 mA:
 - ◆ Average output power = 6 W
 - ◆ Gain = 15 dB
 - ◆ Efficiency = 21 %
 - ◆ ACPR = -42 dBc (at 3.84 MHz)
 - ◆ IMD3 = -38 dBc
- Easy power control
- Excellent ruggedness
- High power gain
- Excellent thermal stability
- Designed for broadband operation (2000 MHz to 2200 MHz)
- Internally matched for ease of use
- ESD protection

1.3 Applications

- RF power amplifiers for W-CDMA base stations and multicarrier applications in the 2000 MHz to 2200 MHz frequency range
- Broadcast drivers

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Symbol
1	drain		,
2	gate		1
3	source		2 3 sym112

^[1] Connected to flange

3. Ordering information

Table 3. Ordering information

Type number	Package	9	
	Name	Description	Version
BLF3G22-30	-	flanged ceramic package; 2 mounting holes; 2 leads	SOT608A

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-	±15	V
I_D	drain current		-	12	Α
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	200	°C

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5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-case)}	thermal resistance from junction to case	T _h = 25 °C	<u>1</u> 1.85	K/W

^[1] Thermal resistance is determined under specified RF operating conditions

6. Characteristics

Table 6. Characteristics

 $T_i = 25 \, ^{\circ}\text{C}$ unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.7 \text{ mA}$	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	$V_{DS} = 10 \text{ V}; I_{D} = 70 \text{ mA}$	2.0	-	3.0	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 26 \text{ V}$	-	-	1.5	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 9 V;$ $V_{DS} = 10 V$	9	-	-	Α
I _{GSS}	gate leakage current	V_{GS} = ±15 V; V_{DS} = 0 V	-	-	150	nΑ
g _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 3.5 A	-	3	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 6 V;$ $I_D = 2.5 A$	-	0.3	-	Ω
C _{rs}	feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 26 \text{ V};$ f = 1 MHz	-	1.7	-	pF

7. Application information

Table 7. Application information

Table 7.	Application information					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Mode of o	Mode of operation: Two-tone CW (100 kHz tone spacing); f = 2170 MHz; I _{Dq} = 450 mA					
Gp	power gain	$P_{L(PEP)} = 30 W$	-	14	-	dB
RLin	input return loss	$P_{L(PEP)} = 30 W$	-	–15	-	dB
η_{D}	drain efficiency	$P_{L(PEP)} = 30 W$	-	33	-	%
IMD3 third order intermodulat		$P_{L(PEP)} = 30 W$	-	-24	-	dBc
	distortion	$P_{L(PEP)} < 6 W$	-	< -50	-	dBc
	peration: Two-tone W-CDMA;	· · · · · · · · · · · · · · · · · · ·	- 64 DPC	H with 6	6 % cli _l	oping;
Gp	power gain	$P_{L(AV)} = 6 W$	13	15	-	dB
RLin	input return loss	$P_{L(AV)} = 6 W$	-	-10	-8	dB
η_{D}	drain efficiency	$P_{L(AV)} = 6 W$	18	21	-	%
IMD3	third order intermodulation distortion	$P_{L(AV)} = 6 W$	-	-38	-35	dBc
ACPR	adjacent channel power ratio	$P_{L(AV)} = 6 W$	[1] -	-42	-38	dBc

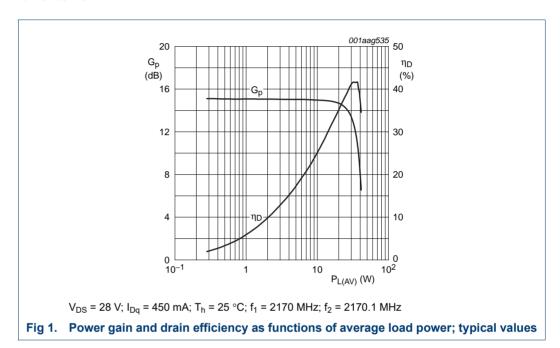
^[1] Measured within 10 kHz bandwidth.

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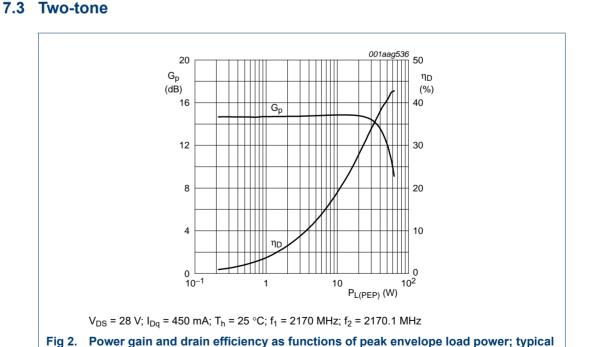
7.1 Ruggedness in class-AB operation

The BLF3G22-30 is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 28 V; I_{Dg} = 450 mA; P_L = 30 W (CW); f = 2170 MHz.

7.2 One-tone

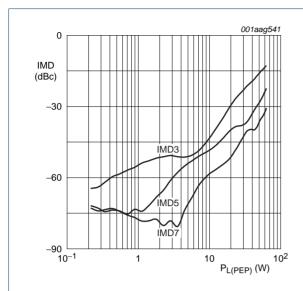


values



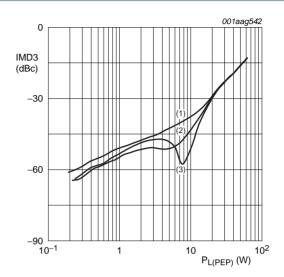
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 V_{DS} = 28 V; I_{Dq} = 450 mA; T_h = 25 °C; f_1 = 2170 MHz; f_2 = 2170.1 MHz

Fig 3. Intermodulation distortion as function of peak envelope load power; typical values



 V_{DS} = 28 V; T_h = 25 °C; f_1 = 2170 MHz; f_2 = 2170.1 MHz

- (1) $I_{Dq} = 400 \text{ mA}$
- (2) $I_{Dq} = 450 \text{ mA}$
- (3) $I_{Dq} = 500 \text{ mA}$

Fig 4. IMD3 as function of peak envelope load power; typical values

7.4 Two-carrier W-CDMA

Input signals: 3GPP W-CDMA, test model 1, 1-64 DPCH with 66 % clipping; peak-to-average power ratio: 8.5 dB at 0.01 % probability on CCDF; channel spacing = 10 MHz; bandwidth = 3.84 MHz.

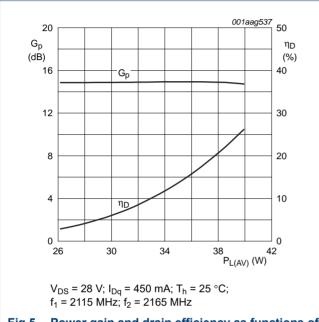


Fig 5. Power gain and drain efficiency as functions of average load power; typical values

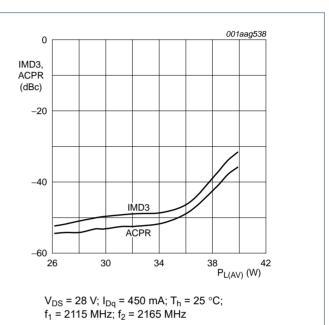


Fig 6. IMD3 and ACPR as functions of average load power; typical values.

7.5 Input impedance and load impedances measured under CW conditions

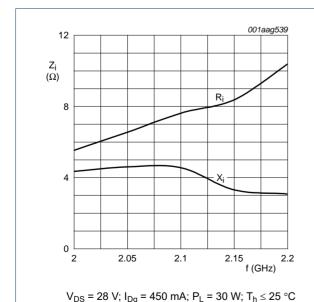
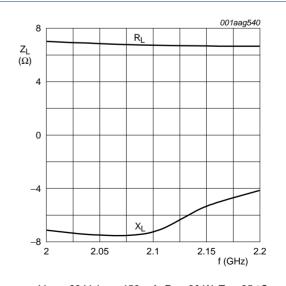


Fig 7. Input impedance as function of frequency (series components); typical values

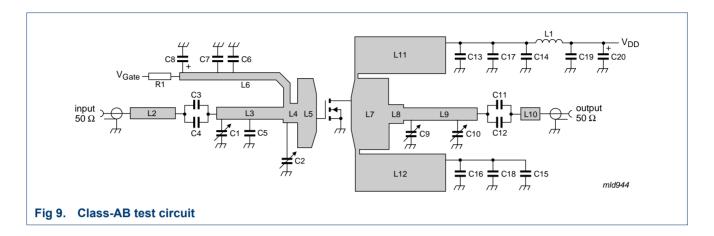


 V_{DS} = 28 V; I_{Dq} = 450 mA; P_L = 30 W; $T_h \le$ 25 °C

Fig 8. Load impedance as function of frequency (series components); typical values

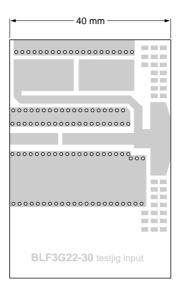
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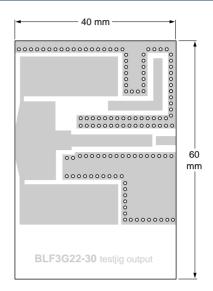
8. Test information

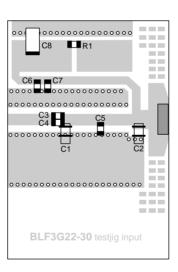


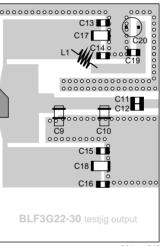
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Dimensions in mm.

The components are situated on one side of the copper-clad Printed-Circuit Board (PCB) with Teflon dielectric (ϵ_r = 2.2); thickness = 0.79 mm.

The other side is unetched and serves as a ground plane.

See Table 8 for list of components.

Fig 10. Component layout for 2.17 GHz class-AB test circuit

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Table 8. List of components (see Figure 9 and Figure 10)

Component	Description		Value	Dimensions	Catalogue No.
C1, C2, C9, C10	Tekelec variable capacitor; type 37271		0.6 pF to 4.5 pF		
C3, C4, C11, C12	multilayer ceramic chip capacitor	<u>[1]</u>	6.8 pF		
C5	multilayer ceramic chip capacitor	[1]	2.2 pF		
C6, C7, C13, C14, C15, C16	multilayer ceramic chip capacitor	[1]	12 pF		
C8	tantalum capacitor		10 μF		
C17, C18	multilayer ceramic chip capacitor		1.5 μF		TDK C3225X7R1H155M
C19	multilayer ceramic chip capacitor	[2]	1 nF		
C20	electrolytic capacitor		100 μF; 63 V		
L1	handmade; enamelled 1 mm copper wire		-	2 loops; 4 mm in diameter	
L2	stripline	[3]	50 Ω	12 mm \times 2.4 mm	
L3	stripline	[3]	43 Ω	18 mm \times 3 mm	
L4	stripline	[3]	29 Ω	$4~mm \times 5~mm$	
L5	stripline	[3]	10 Ω	$5 \text{ mm} \times 18.4 \text{ mm}$	
L6	stripline	[3]	56 Ω	34.4 mm \times 2 mm	
L7	stripline	[3]	9 Ω	10 mm \times 20 mm	
L8	stripline	[3]	29 Ω	$4~mm \times 5~mm$	
L9	stripline	[3]	41 Ω	20 mm \times 3.2 mm	
L10	stripline	[3]	50 Ω	$5~\text{mm} \times 2.4~\text{mm}$	
L11, L12	stripline	[3]	17 Ω	24.5 mm × 10 mm	

^[1] American Technical Ceramics type 100A or capacitor of same quality.

^[2] American Technical Ceramics type 100B or capacitor of same quality.

^[3] The striplines are on a double copper-clad Printed-Circuit Board (PCB) with Teflon dielectric (ε_r = 2.2); thickness = 0.79 mm.

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9. Package outline

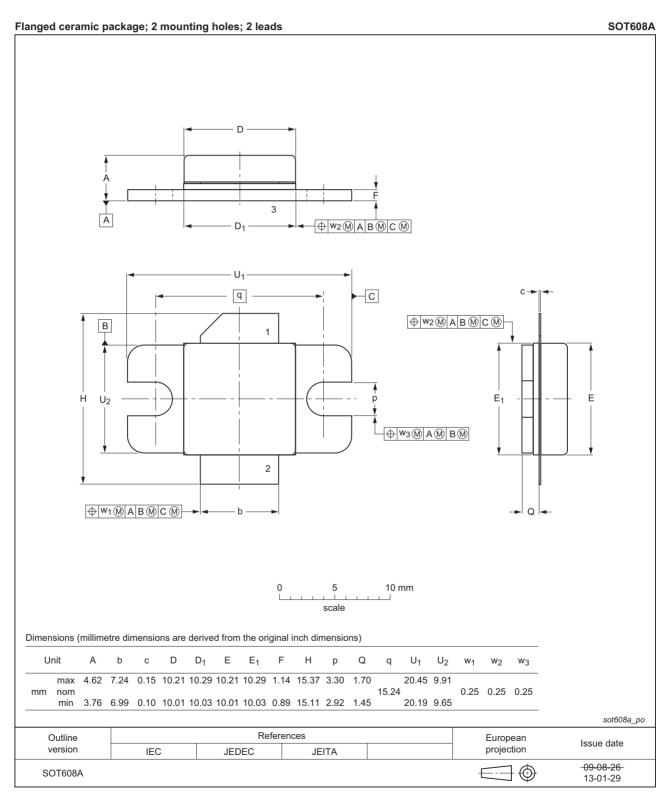


Fig 11. Package outline SOT608A

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10. Abbreviations

Table 9. Abbreviations

Acronym	Description
3GPP	Third Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
LDMOS	Laterally Diffused Metal Oxide Semiconductor
RF	Radio Frequency
UHF	Ultra High Frequency
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

11. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BLF3G22-30#2	20150901	Product data sheet - BLF30		BLF3G22-30_1		
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. 					
	Legal texts have been adapted to the new company name where appropriate.					
BLF3G22-30_1	20070621	Product data sheet	-	-		

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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